To our customers,

Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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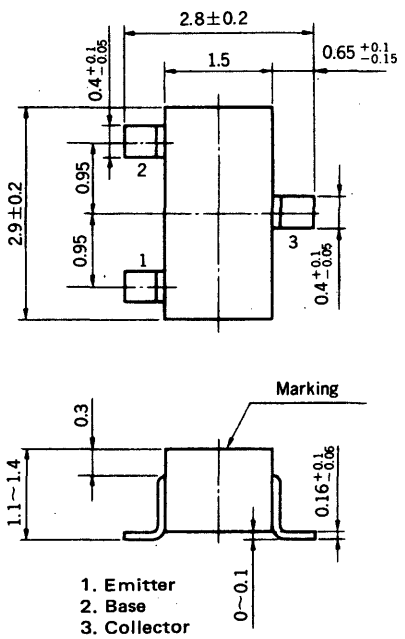
(Note 2) “Renesas Electronics product(s)” means any product developed or manufactured by or for Renesas Electronics.

RENESAS

SILICON TRANSISTOR
2SA1462

HIGH SPEED SWITCHING
PNP SILICON EPITAXIAL TRANSISTOR
MINI MOLD

PACKAGE DIMENSIONS
in millimeters



FEATURES

- High Speed Switching : t_{on} = 9.0 ns TYP.
  t_{off} = 19.0 ns TYP.
- High f_T : f_T = 1 800 MHz TYP.
- Low C_{ob} : C_{ob} = 2.0 pF TYP.
- Complementary to 2SC3735

ABSOLUTE MAXIMUM RATINGS

Maximum Voltages and Current (T_a = 25 °C)			
Collector to Base Voltage	V_{CBO}	−15	V
Collector to Emitter Voltage	V_{CEO}	−15	V
Emitter to Base Voltage	V_{EBO}	−4.5	V
Collector Current (DC)	I_C	−50	mA
Maximum Power Dissipation			
Total power Dissipation at 25 °C Ambient Temperature	P_T	200	mW
Maximum Temperatures			
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	−55 to +150	°C

ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Cutoff Current	I_{CBO}			−100	nA	V_{CB} = −8.0 V, I_E = 0
Emitter Cutoff Current	I_{EBO}			−100	nA	V_{EB} = −3.0 V, I_C = 0
DC Current Gain	h_{FE1} *	30	70			V_{CE} = −1.0 V, I_C = −1.0 mA
DC Current Gain	h_{FE2} *	50	80	150		V_{CE} = −1.0 V, I_C = −10 mA
Collector Saturation Voltage	$V_{CE(sat)}$ *		−0.09	−0.20	V	I_C = −10 mA, I_B = −1.0 mA
Base Saturation Voltage	$V_{BE(sat)}$ *		−0.80	−0.95	V	I_C = −10 mA, I_B = −1.0 mA
Gain Bandwidth Product	f_T	800	1800		MHz	V_{CE} = −10 V, I_E = 10 mA
Output Capacitance	C_{ob}		2.0	3.0	pF	V_{CB} = −5.0 V, I_E = 0, f = 1.0 MHz
Turn-on Time	t_{on}		9.0	20	ns	I_C = −10 mA I_{B1} = −I_{B2} = −1.0 mA
Storage Time	t_{stg}		16	40	ns	
Turn-off Time	t_{off}		19	40	ns	

* Pulsed: PW ≦ 350 μs, Duty Cycle ≦ 2 %

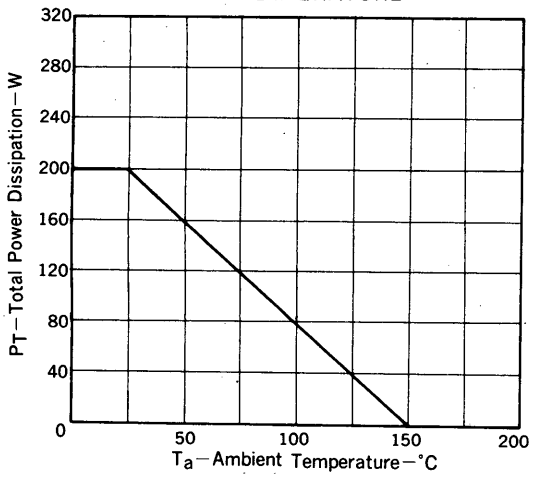
h_{FE2} Classification

Making	Y33	Y34
h_{FE2}	50 to 100	75 to 150

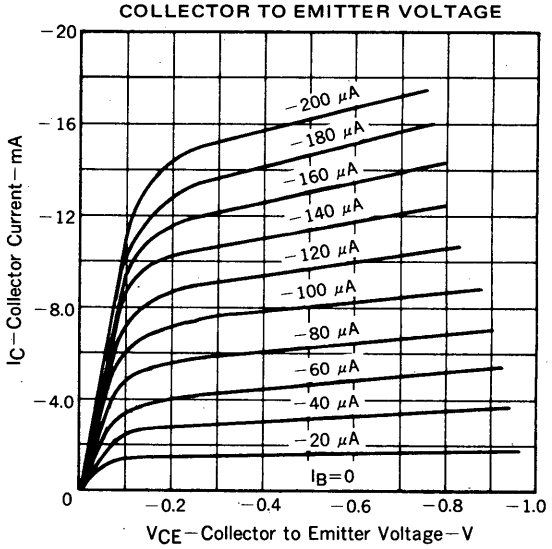
NEC Corporation

TYPICAL CHARACTERISTICS (T_a = 25 °C)

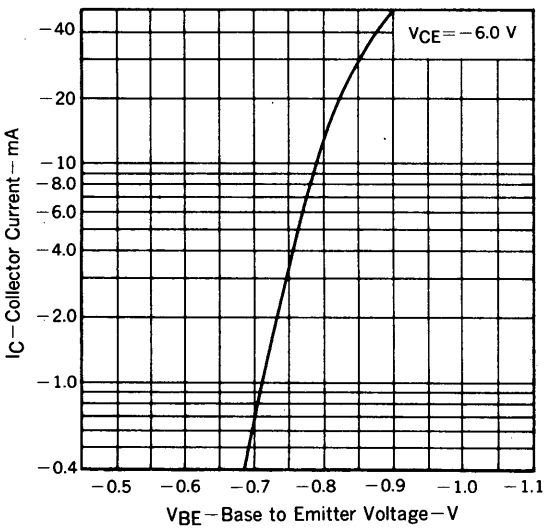
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



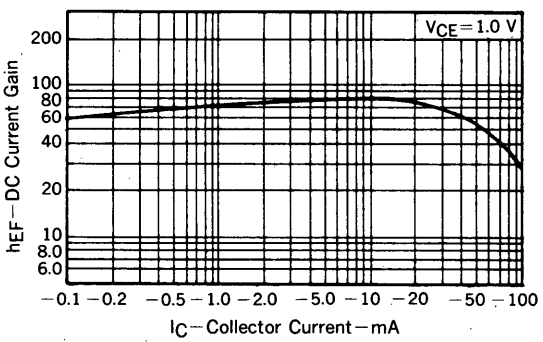
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



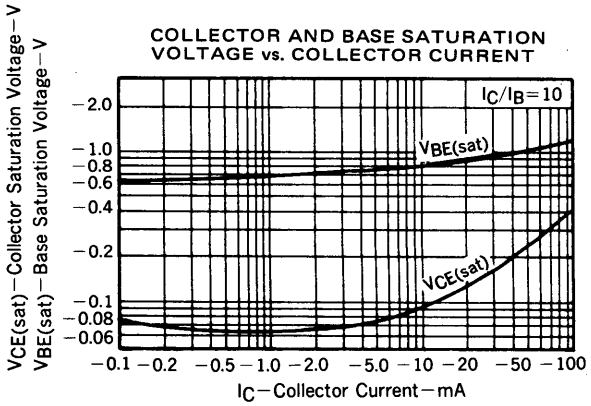
COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



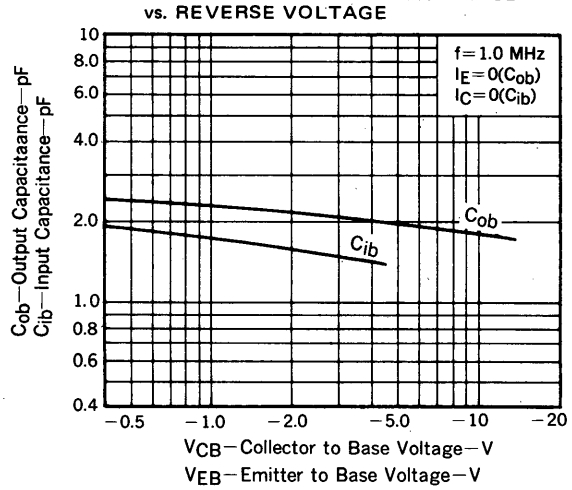
DC CURRENT GAIN vs. COLLECTOR CURRENT



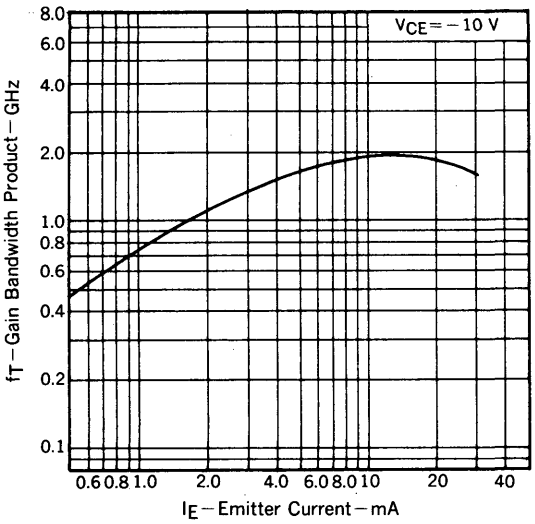
COLLECTOR AND BASE SATURATION VOLTAGE vs. COLLECTOR CURRENT



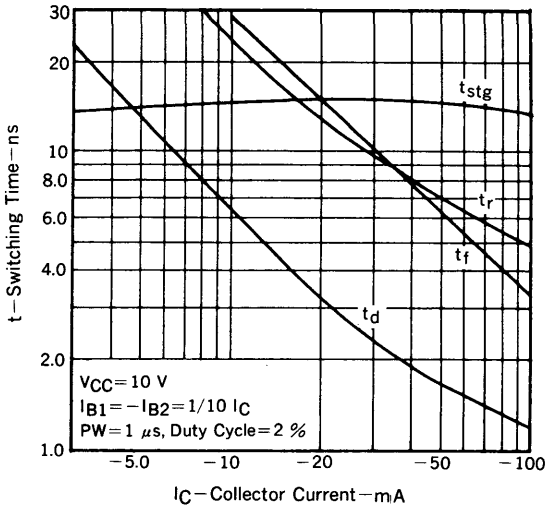
INPUT AND OUTPUT CAPACITANCE vs. REVERSE VOLTAGE



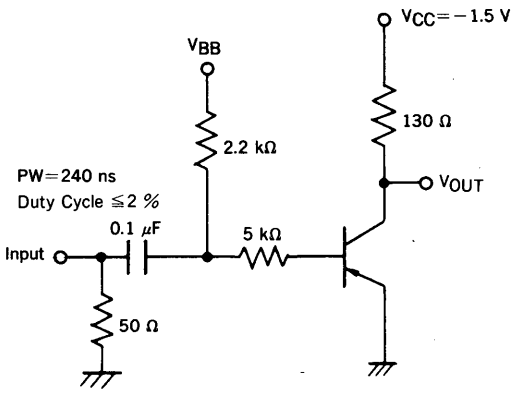
GAIN BANDWIDTH PRODUCT vs. EMITTER CURRENT



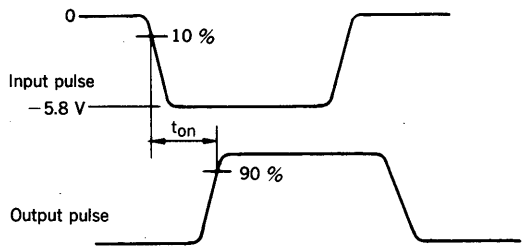
SWITCHING TIME vs. COLLECTOR CURRENT



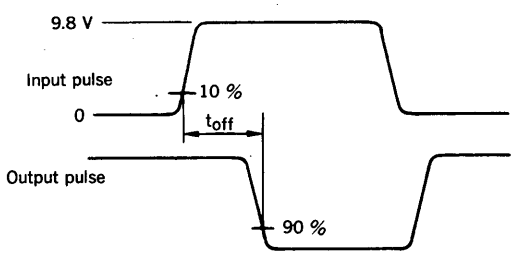
SWITCHING TIME TEST CIRCUIT



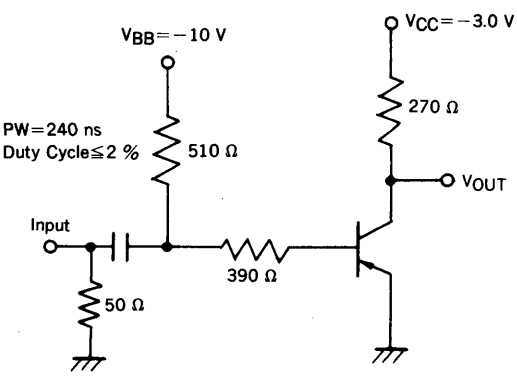
t_{on}, t_{off} Switching



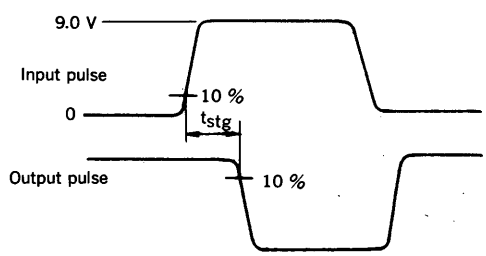
t_{on} Voltage Waveforms (V_{BB} = GROUND)



t_{off} Voltage Waveforms (V_{BB} = −8.0 V)



t_{stg} Switching



t_{stg} Voltage Waveforms

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